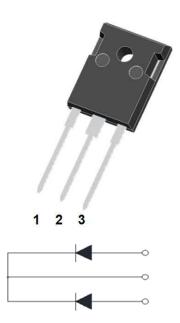




# **Schottky Diodes**



### **Features**

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

### **Typical Applications**

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

#### **Mechanical Data**

• Package: TO-247AB

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free

• Terminals: Tin plated leads, solderable per

J-STD-002 and JESD22-B102

• Polarity: As marked

### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

<u> </u>				
PARAMETER	SYMBOL	UNIT	MBR30150PT	
Device marking code			MBR30150PT	
Repetitive Peak Reverse Voltage	$V_{RRM}$	V	150	
Average Rectified Output Current @60Hz sine wave, R-load, Tc=150°C	Io	Α	30	
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25°C	I <sub>FSM</sub>	Α	250	
Current Squared Time @1ms≤t≤8.3ms Tj=25°C	l²t	A <sup>2</sup> s	260	
Storage Temperature	$T_{stg}$	°C	-55 ~ +175	
Junction Temperature	Tj	°C	-55 ~ +175	

### **■**Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Тур	Max
Peak Forward Voltage	$V_{FM}$	V	I <sub>FM</sub> =15.0A Tj=25°C	0.5	0.81	0.85
			I <sub>FM</sub> =15.0A Tj=125℃	-	0.67	0.72
DC reverse current at rated DC blocking voltage per diode	I <sub>RRM1</sub>	mA	V <sub>RM</sub> =V <sub>RRM</sub> Tj=25°C	-	-	0.1
	I <sub>RRM2</sub>		V <sub>RM</sub> =V <sub>RRM</sub> Tj=125°C	-	-	20
Junction capacitance	Cj		1MHz and Applied Reverse Voltage of 4.0 V.D.C	150	310	550

Note1:Pulse test:300uS pulse widh,1% duty cycle

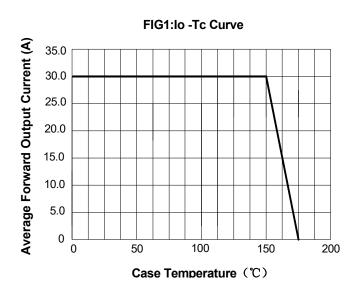
Note2:Pulse test:pulse widh 40mS

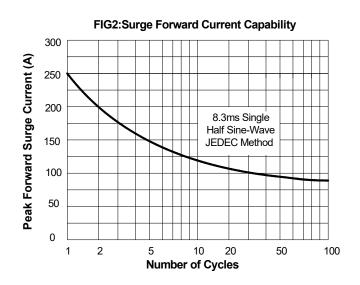
## MBR30150PT-B1-W5094HF

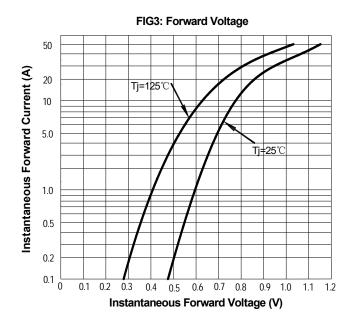
## **■Thermal Characteristics** (T<sub>a</sub>=25°C Unless otherwise specified)

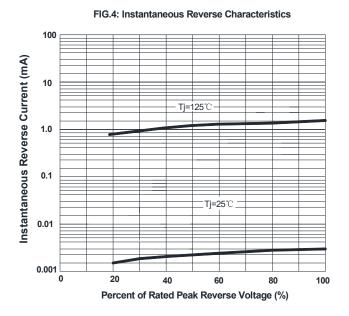
	PARAMETER	SYMBOL	UNIT	MBR30150PT
Thermal	Between junction and ambient	$R_{\theta J-A}$	°C/W	50.0
Resistance	Between junction and case	$R_{ heta J ext{-}C}$	°C/W	1.0

## **■Characteristics** (Typical)





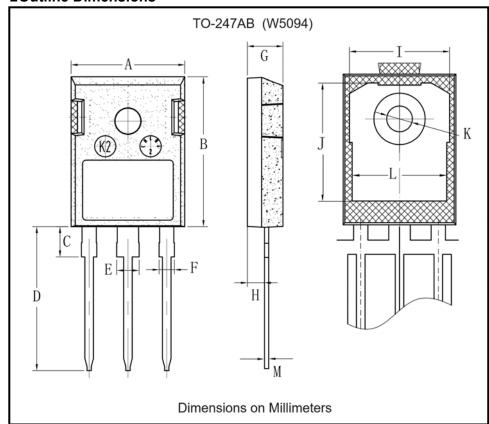






# MBR30150PT-B1-W5094HF

## **■**Outline Dimensions



TO-247AB						
Dim	Min	Max				
Α	15.72	16.12				
В	20.70	21.10				
С	4.02	4.42				
D	19.90	20.30				
Е	3.00	3.30				
F	2.00	2.30				
G	4.80	5.20				
Н	2.30	2.50				
I	TYP 14.02					
J	TYP 16.55					
K	3.50	3.70				
L	TYP 13.26					
М	0.58	0.62				



## MBR30150PT-B1-W5094HF

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